## NSN 5961-01-071-4058

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-071-4058 **Inclosure Material:** Plastic **Overall Length:** Between 0.590 inches and 0.610 inches **Terminal Length:** 0.355 inches **Overall Height:** Between 0.370 inches and 0.395 inches **Overall Width:** Between 0.180 inches and 0.200 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 repetitive peak reverse voltage and 50.0 working peak reverse voltage and 35.0 reverse voltage, total rms **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute and 30.00 amperes forward current, average preset **Power Rating Per Characteristic:** 3.2 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: